

700V N-Channel MOSFET

TO-220F

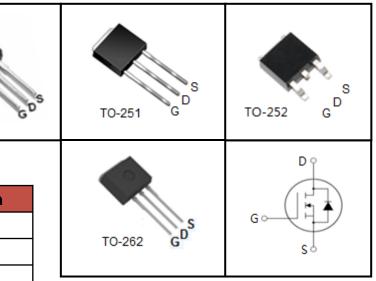
FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

Device Marking and Package Information					
Device	Package	Marking			
CS6N70F	TO-220F	CS6N70F			
CS6N70K	TO-262	CS6N70K			
CS6N70U	TO-251	CS6N70U			
CS6N70D	TO-252	CS6N70D			



Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted							
Parameter	Symbol		Unit				
	Symbol	TO-220F	TO-262	TO-251	TO-252	Unit	
Drain-Source Voltage ($V_{GS} = 0V$)	V _{DSS}	700			V		
Continuous Drain Current	I _D	6			А		
Pulsed Drain Current (note1	I _{DM}	24				А	
Gate-Source Voltage	V _{GSS}	±30		V			
Single Pulse Avalanche Energy (note2)	E _{AS}	145			mJ		
Avalanche Current (note1	I _{AS}	5.4			А		
Repetitive Avalanche Energy (note1)	E _{AR}	87			mJ		
Power Dissipation ($T_c = 25^{\circ}C$)	P _D	63 97			W		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150			°C		

Thermal Resistance						
Baramatar	Symbol	Value				
Parameter		TO-220F	TO-262	TO-251	TO-252	Unit
Thermal Resistance, Junction-to-Case	R _{thJC}	1.98	1.29		°C/W	
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62.5	60		-0/10	



CS6N70F,CS6N70K,CS6N70U,CS6N70D

Devementer						
Parameter	Symbol	Test Conditions	Min.	Typ. Max.		Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250 \mu A$	700			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 700V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = = 250 \mu A$	3.0		4.0	V
Drain-Source On-Resistance (Note3)	R _{DS(on)}	V _{GS} = 10V, I _D = 3.0A		1.3	1.6	Ω
Dynamic						
Input Capacitance	C _{iss}	$\mathcal{V} = \mathcal{O}\mathcal{V}$		880		pF
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 25V,$		84.5		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		10		
Total Gate Charge	Q _g			30		nC
Gate-Source Charge	Q _{gs}	$V_{DD} = 560V, I_D = 6.0A, V_{GS} = 10V$		4.2		
Gate-Drain Charge	Q_{gd}			15		
Turn-on Delay Time	t _{d(on)}			38		
Turn-on Rise Time	t _r	V _{DD} = 350V, I _D =6.0A,		17		
Turn-off Delay Time	t _{d(off)}	$V_{\text{DD}} = 350\text{V}, \text{ I}_{\text{D}} = 6.0\text{A}, \\ \text{R}_{\text{G}} = 25 \ \Omega$		134		ns
Turn-off Fall Time	t _f			35		
Drain-Source Body Diode Character	istics					
Continuous Body Diode Current	۱ _s	T 0500			6	A
Pulsed Diode Forward Current	I _{SM}	T _C = 25 °C			24	
Body Diode Voltage	V _{SD}	$T_J = 25^{\circ}C, I_{SD} = 3A, V_{GS} = 0V$			1.4	V
Reverse Recovery Time	t _{rr}	V _{GS} = 0V,I _S = 6.0A,		621.5		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt =100A /µs		1.67		μC

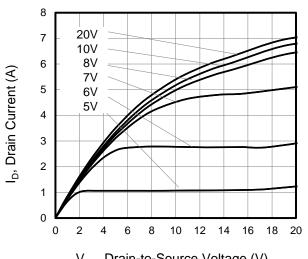
Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=10mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 °C
- 3. Pulse Test: Pulse width \leq 300µs, Duty Cycle \leq 1%

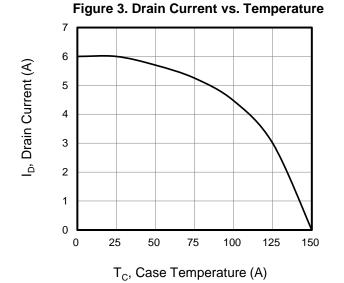


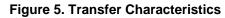
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

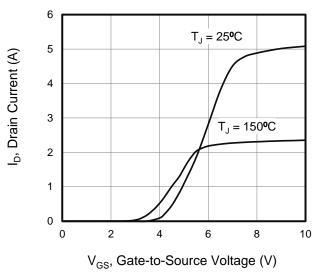
Figure 1. Output Characteristics (T_J = 25°C)

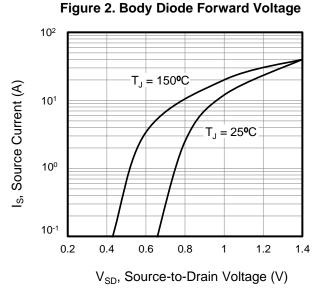


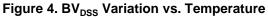
 V_{DS} , Drain-to-Source Voltage (V)

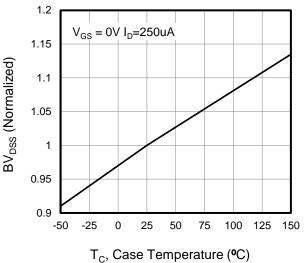




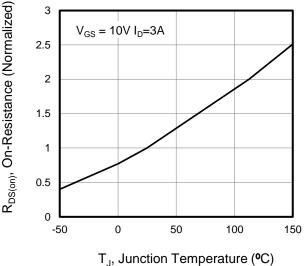






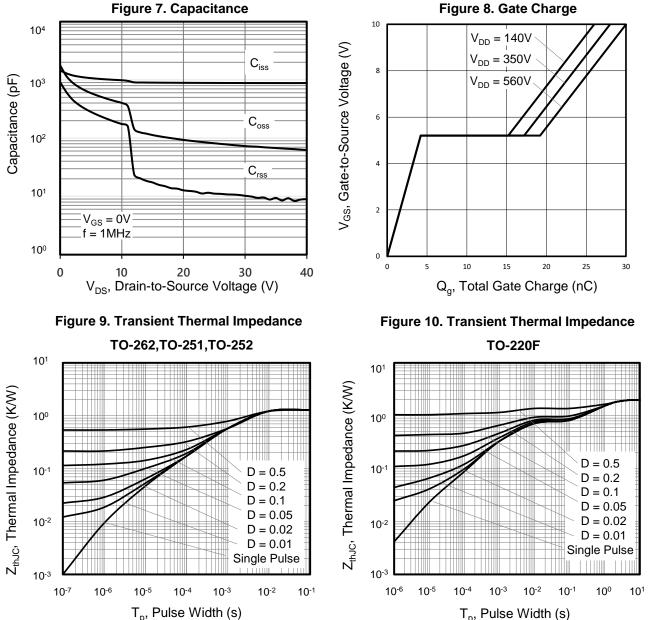








Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted



T_p, Pulse Width (s)



Figure A: Gate Charge Test Circuit and Waveform

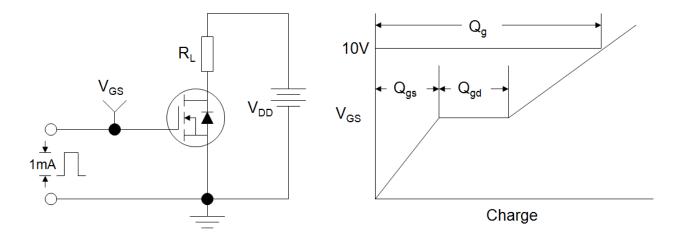


Figure B: Resistive Switching Test Circuit and Waveform

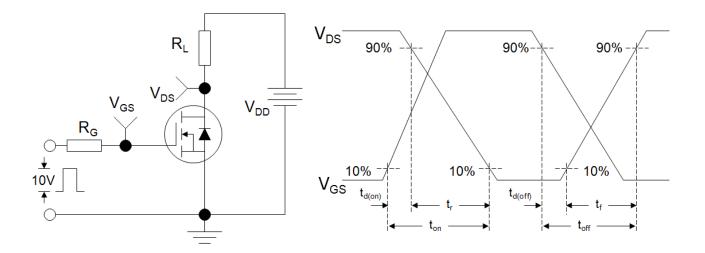
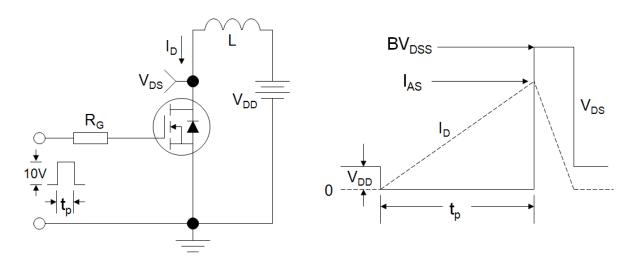
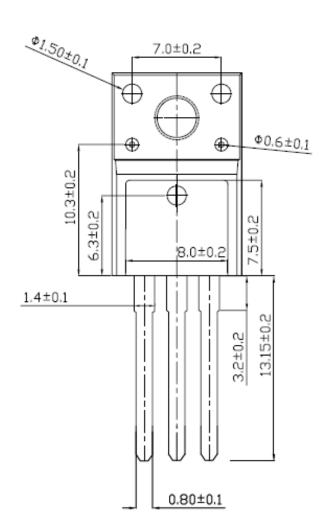


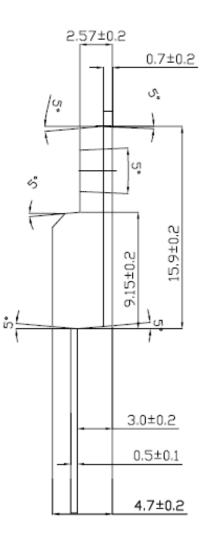
Figure C: Unclamped Inductive Switching Test Circuit and Waveform





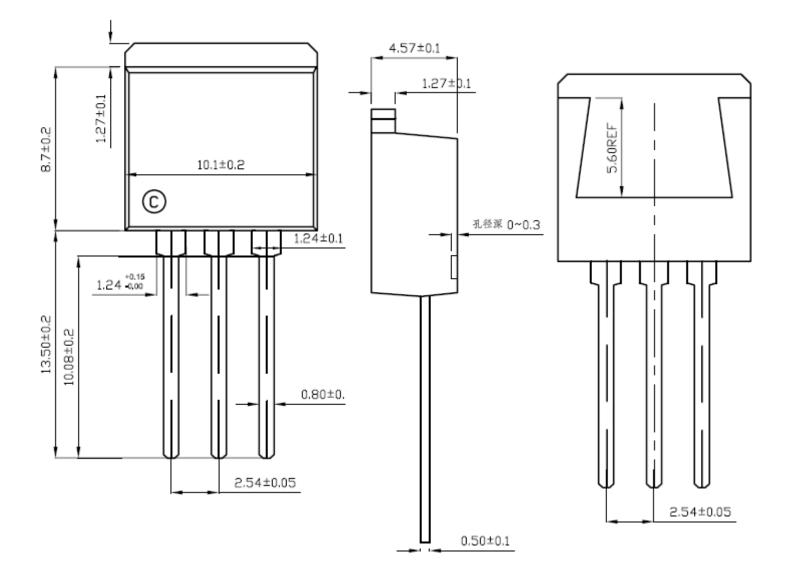
TO-220F







TO-262

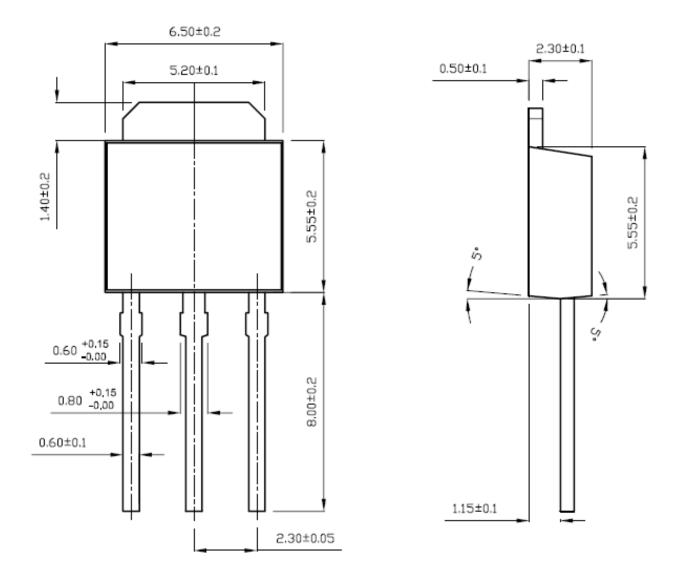


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CS6N70F,CS6N70K,CS6N70U,CS6N70D

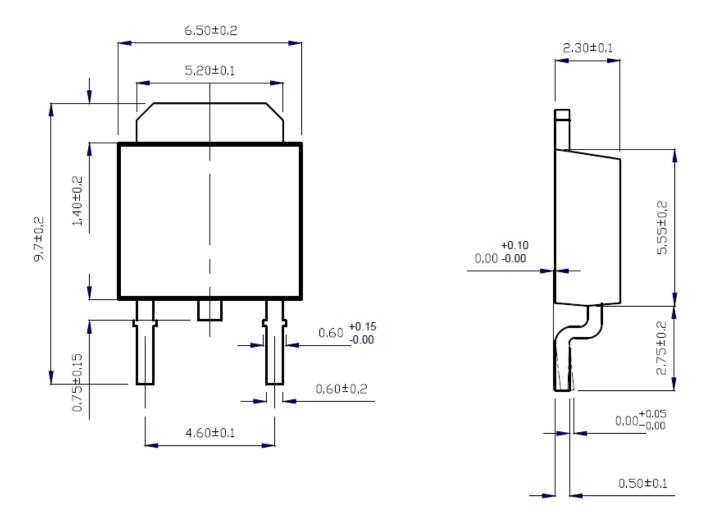
TO-251



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TO-252





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